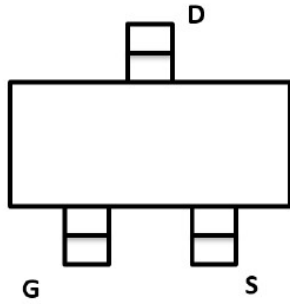
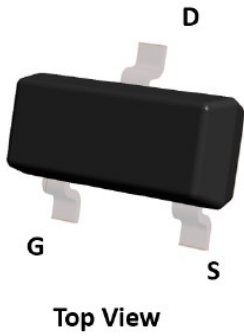
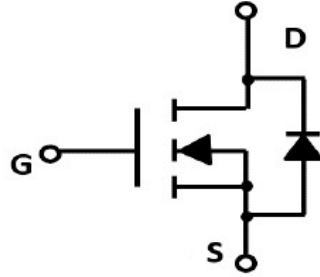


## N-Channel Enhancement Mode Field Effect Transistor



**SOT-23**



### Product Summary

- $V_{DS}$  20V
- $I_D$  6.8A
- $R_{DS(ON)}$ ( at  $V_{GS}=4.5V$ ) < 18mohm
- $R_{DS(ON)}$ ( at  $V_{GS}=2.5V$ ) < 22mohm
- $R_{DS(ON)}$ ( at  $V_{GS}=1.8V$ ) < 39mohm
- 100%  $\nabla V_{DS}$  Tested

### General Description

- Trench Power LV MOSFET technology
- High Power and current handling capability

### Applications

- PWM applications
- Load switch

### ■ Absolute Maximum Ratings ( $T_A=25^\circ C$ unless otherwise noted)

| Parameter   | Symbol          | Limit            | Unit         |
|---|-----------------|------------------|--------------|
| Drain-source Voltage                                | $V_{DS}$        | 20               | V            |
| Gate-source Voltage                                 | $V_{GS}$        | $\pm 10$         | V            |
| Drain Current                                       | $I_D$           | $T_A=25^\circ C$ | 6.8          |
|   |                 | $T_A=70^\circ C$ | 5.4          |
| Pulsed Drain Current <sup>A</sup>                   | $I_{DM}$        | 27               | A            |
| Total Power Dissipation                             | $P_D$           | $T_A=25^\circ C$ | 1.25         |
|   |                 | $T_A=70^\circ C$ | 0.8          |
| Thermal Resistance Junction-to-Ambient <sup>B</sup> | $R_{\theta JA}$ | 100              | $^\circ C/W$ |
| Junction and Storage Temperature Range              | $T_J, T_{STG}$  | -55~+150         | $^\circ C$   |

### ■ Ordering Information (Example)

| PREFERRED P/N | PACKING CODE | Marking | MINIMUM PACKAGE(pcs) | INNER BOX QUANTITY(pcs) | OUTER CARTON QUANTITY(pcs) | DELIVERY MODE |
|---------------|--------------|---------|----------------------|-------------------------|----------------------------|---------------|
| YJL2312A      | F2           | S12.    | 3000                 | 30000                   | 120000                     | 7" reel       |



# YJL2312A

## ■ Electrical Characteristics (T<sub>J</sub>=25°C unless otherwise noted)

| Parameter                         | Symbol              | Conditions  | Min  | Typ   | Max  | Units |
|-----------------------------------|---------------------|---|------|-------|------|-------|
| <b>Static Parameter</b>           |                     |   |      |       |      |       |
| Drain-Source Breakdown Voltage    | BV <sub>DSS</sub>   | V <sub>GS</sub> =0V, I <sub>D</sub> =250μA  | 20   |       |      | V     |
| Zero Gate Voltage Drain Current   | I <sub>DSS</sub>    | V <sub>DS</sub> =20V, V <sub>GS</sub> =0V   |      |       | 1    | μA    |
| Gate-Body Leakage Current         | I <sub>GSS</sub>    | V <sub>GS</sub> =±10V, V <sub>DS</sub> =0V  |      |       | ±100 | nA    |
| Gate Threshold Voltage            | V <sub>GS(th)</sub> | V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250μA                                  | 0.45 | 0.62  | 1.0  | V     |
| Static Drain-Source On-Resistance | R <sub>DS(on)</sub> | V <sub>GS</sub> =4.5V, I <sub>D</sub> =6.8A   |      | 13.5  | 18   | mΩ    |
|                                   |                     | V <sub>GS</sub> =2.5V, I <sub>D</sub> =3A   |      | 17    | 22   |       |
|                                   |                     | V <sub>GS</sub> =1.8V, I <sub>D</sub> =2.5A   |      | 22    | 39   |       |
| Diode Forward Voltage             | V <sub>SD</sub>     | I <sub>S</sub> =6.8A, V <sub>GS</sub> =0V   |      |       | 1.2  | V     |
| <b>Dynamic Parameters</b>         |                     |   |      |       |      |       |
| Input Capacitance                 | C <sub>iss</sub>    | V <sub>DS</sub> =10V, V <sub>GS</sub> =0V, f=1MHZ   |      | 888   |      | pF    |
| Output Capacitance                | C <sub>oss</sub>    |   |      | 133   |      |       |
| Reverse Transfer Capacitance      | C <sub>rss</sub>    |   |      | 117   |      |       |
| <b>Switching Parameters</b>       |                     |   |      |       |      |       |
| Total Gate Charge                 | Q <sub>g</sub>      | V <sub>GS</sub> =4.5V, V <sub>DS</sub> =10V, I <sub>D</sub> =6.8A                         |      | 11.05 |      | nC    |
| Gate-Source Charge                | Q <sub>gs</sub>     |   |      | 1.73  |      |       |
| Gate-Drain Charge                 | Q <sub>gd</sub>     |   |      | 3.1   |      |       |
| Turn-on Delay Time                | t <sub>D(on)</sub>  | V <sub>GS</sub> =4.5V, V <sub>DS</sub> =10V, I <sub>D</sub> =6.8A<br>R <sub>GEN</sub> =3Ω |      | 7     |      | ns    |
| Turn-on Rise Time                 | t <sub>r</sub>      |   |      | 46    |      |       |
| Turn-off Delay Time               | t <sub>D(off)</sub> |   |      | 30    |      |       |
| Turn-off fall Time                | t <sub>f</sub>      |   |      | 52    |      |       |

A. Pulse Test: Pulse Width ≤ 300us, Duty cycle ≤ 2%.

B. R<sub>θJA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance, where the case thermal reference is defined as the solder mounting surface of the drain pins. R<sub>θJC</sub> is guaranteed by design, while R<sub>θJA</sub> is determined by the board design. The maximum rating presented here is based on mounting on a 1 in 2 pad of 2oz copper.

## ■ Typical Performance Characteristics



Figure1. Output Characteristics

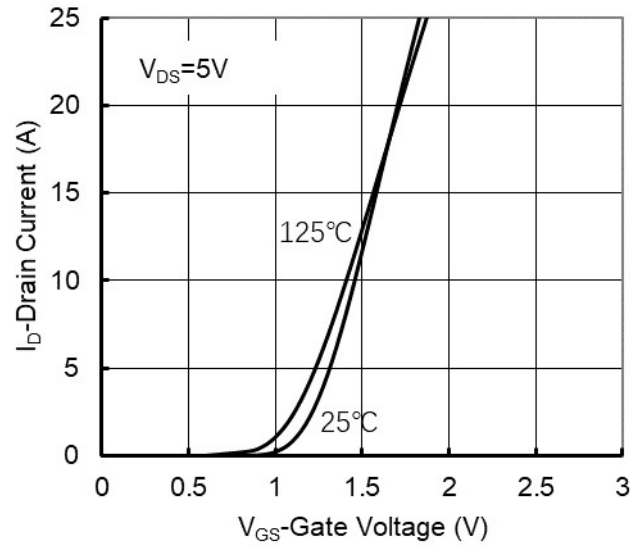


Figure2. Transfer Characteristics

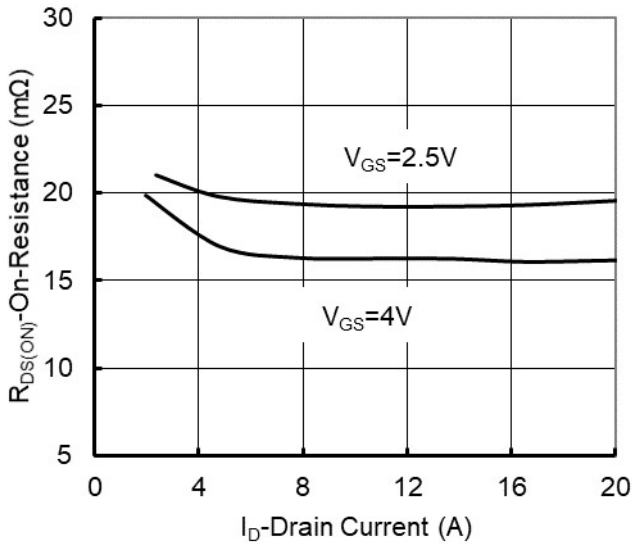


Figure 3: On-Resistance vs. Drain Current and Gate Voltage

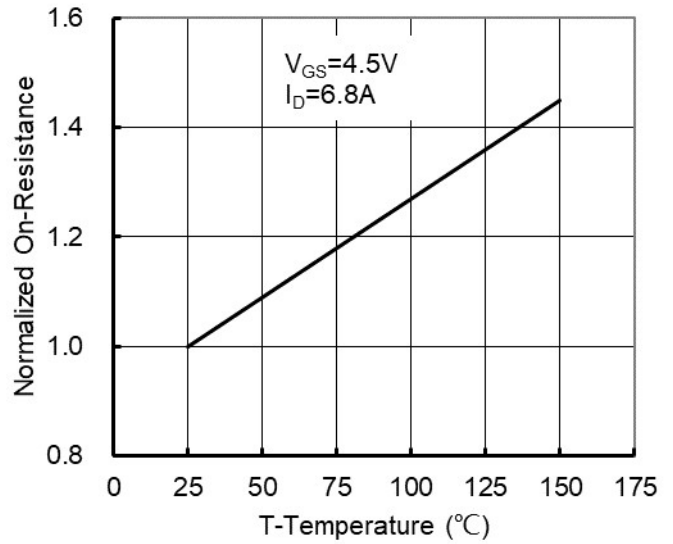


Figure 4: On-Resistance vs. Junction Temperature



Figure5. Capacitance Characteristics



Figure6. Gate Charge



# YJL2312A

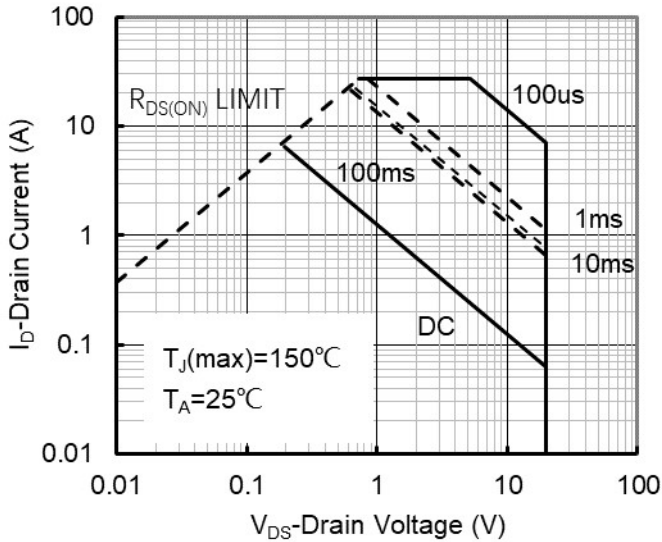


Figure7. Safe Operation Area

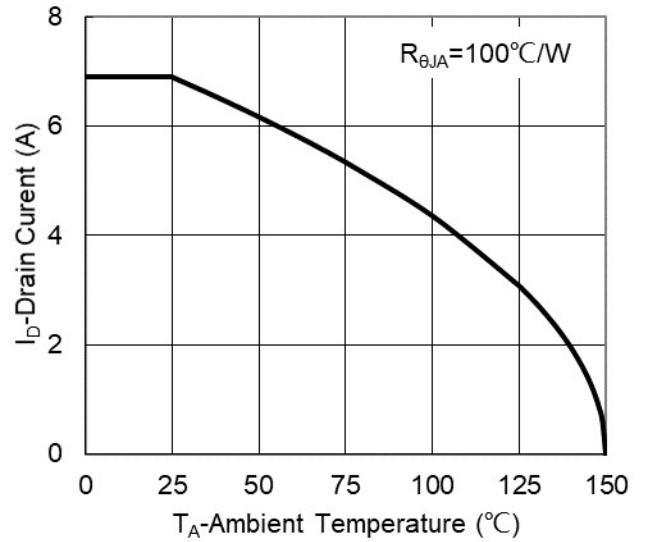


Figure8. Maximum Continuous Drain Current vs Ambient Temperature

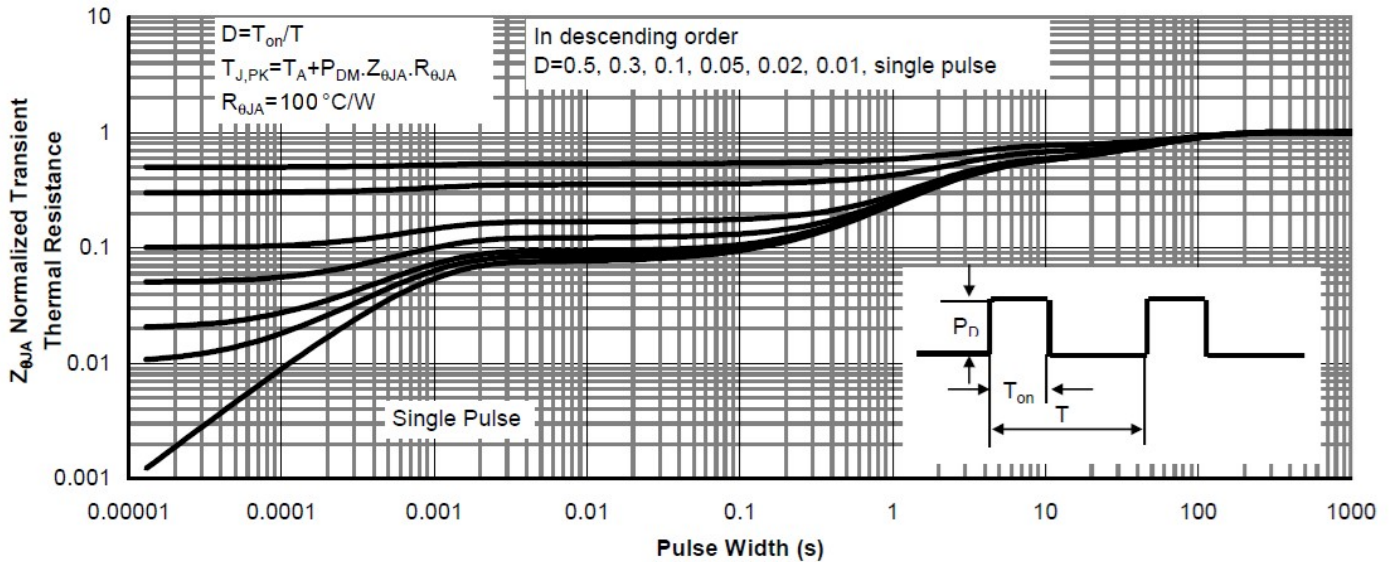
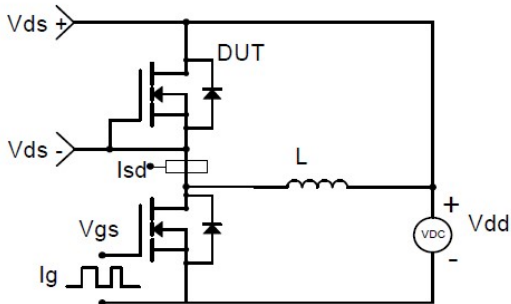


Figure9. Normalized Maximum Transient Thermal Impedance



**Resistive Switching Test Circuit & Waveforms**



**Diode Recovery Test Circuit & Waveforms**



**Gate Charge Test Circuit & Waveform**

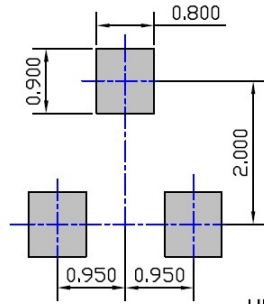
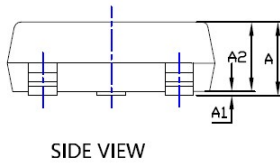
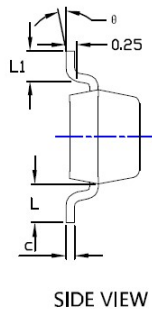
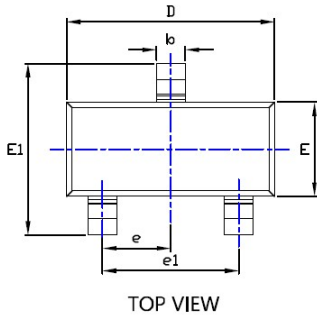


**Unclamped Inductive Switching (UIS) Test Circuit & Waveforms**



# YJL2312A

## ■ SOT-23 Package information



UNIT: mm

| SYMBOL | DIMENSIONS |       |       |            |       |       |
|--------|------------|-------|-------|------------|-------|-------|
|        | INCHES     |       |       | Millimeter |       |       |
|        | MIN.       | NOM.  | MAX.  | MIN.       | NOM.  | MAX.  |
| A      | 0.035      | ---   | 0.045 | 0.900      | ---   | 1.150 |
| A1     | 0.000      | ---   | 0.004 | 0.000      | ---   | 0.100 |
| A2     | 0.035      | 0.038 | 0.041 | 0.900      | 0.975 | 1.050 |
| b      | 0.012      | 0.016 | 0.020 | 0.300      | 0.400 | 0.500 |
| c      | 0.004      | ---   | 0.008 | 0.100      | ---   | 0.200 |
| D      | 0.110      | 0.114 | 0.118 | 2.800      | 2.900 | 3.000 |
| E      | 0.047      | 0.051 | 0.055 | 1.200      | 1.300 | 1.400 |
| E1     | 0.089      | 0.094 | 0.100 | 2.250      | 2.400 | 2.550 |
| e      | 0.037TYP   |       |       | 0.950TYP   |       |       |
| e1     | 0.071      | 0.075 | 0.079 | 1.800      | 1.900 | 2.000 |
| L      | 0.022REF   |       |       | 0.550REF   |       |       |
| L1     | 0.012      | 0.016 | 0.200 | 0.300      | 0.400 | 0.500 |
| θ      | 0°         | ---   | 8°    | 0°         | ---   | 8°    |

NOTE:

- 1.PACKAGE BODY SIZES EXCLUDE MOLD FLASH AND GATE BURRS.
- 2.TOLERANCE 0.1mm UNLESS OTHERWISE SPECIFIED.
- 3.THE PAD LAYOUT IS FOR REFERENCE PURPOSES ONLY.



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